Diode Semiconductor Device - Page 1 of 1



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Inclosure	Material:

Metal

Overall Length:

0.082 inches

Terminal Length:

0.064 inches

Overall Diameter:

0.084 inches

End Application:

Radar

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1.0 reverse voltage, peak

Current Rating Per Characteristic:

15.00 milliamperes source cutoff current preset

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Terminal Type And Quantity:

2 ferrule

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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